

IN THE CLAIMS

Claims 1-20 (Canceled)

21. (Currently Amended) A semiconductor device comprising:
a plurality of power supply systems each supplying power to a plurality of circuits, and
a control circuit transmitting first control signals to said plurality of power supply
systems,

said plurality of power supply systems receiving said first control signals from said
control circuit to supply power to a group of desired circuits,

wherein said plurality of power supply systems notify said control circuit that supply of
power is started.

22. (Cancelled)

23. (Previously presented) The semiconductor device according to claim 21, wherein
said control circuit controls transmission of second control signals after said power supply
systems have started supply of power to said group of the desired circuits.

24. (Previously presented) A semiconductor device comprising:
a substrate in which a circuit exists, and
a power supply system supplying a potential of said substrate,
said power supply system switching between a first case in which the substrate potential
satisfies a first voltage condition in the forward direction with respect to the conductivity of

source-drain of a transistor and a second case in which the substrate potential satisfies a second voltage condition of a value smaller than that of the first voltage condition.

25. (Previously presented) The semiconductor device according to claim 24, wherein a control circuit transmitting a control signal to said power supply system is provided inside the semiconductor device,

said power supply system receives said control signal from said control circuit to supply power to a group of the desired circuits.

26. (Previously presented) The semiconductor device according to claim 24, wherein said first voltage condition is selected when said circuit is in an active condition, and said second voltage condition is selected when said circuit is in a standby condition.